

N-Channel 40-V (D-S) MOSFET

Description

The MS40N05 is a high performance trench N-ch MOSFETs with extreme high cell density, which provide excellent $R_{DS(ON)}$ and gate charge for most of the small power switching and load switch applications.

The device meets the RoHS and Green Product requirement with full function reliability approved.

Features

- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent CdV/dt effect decline
- Green Device Available

Typical Applications

- Notebook
- Load Switch
- Hand-held Instrument

Package type: SOT-23

Packing & Order Information

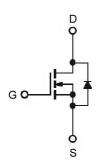
3,000/Reel



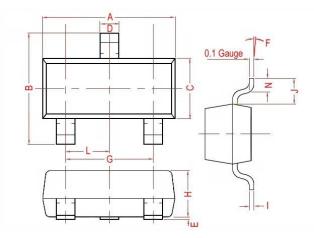


RoHS Compliant

Graphic Symbol

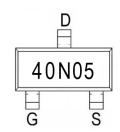


Package Dimension



REF.	Millimeter		REF.	Millimeter		
	Min.	Max.	KEF.	Min.	Max.	
Α	2.70	3.10	G	1.90 Ref.		
В	2.30	3.00	Н	0.90	1.30	
С	1.20	1.75	I	0.05	0.21	
D	0.30	0.50	J	0.58 Ref.		
E	0.01	0.15	L	0.95 Typ.		
F	0°	10°	N	0.20 Min.		

Marking





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MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings (unless otherwise specified)					
Symbol	Parameter	Value	Units		
V _{DS}	Drain-Source Voltage	40	V		
V _G s	Gate-Source Voltage	±20	V		
l _n	Continuous Drain Current ¹ (T _A =25°C)	5	А		
ID	Continuous Drain Current ¹ (T _A =70°C)	4.1	Α		
I _{DM}	Pulsed Drain Current ² (T _A =25°C)	16	А		
Po	Power Dissipation ³ (T _A =25°C)	1.25	W		
TJ/Tstg	Operating Junction and Storage Temperature	-55 to +150	°C		

Thermal Resistance Ratings					
Symbol	Parameter	Maximum	Units		
RθJA	Maximum Junction-to-Ambient ³	100	°C/W		

Electrical Characteristics(T」=25°C unless otherwise specified)						
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
$V_{GS\ (th)}$	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250μA	1.0	-	2.5	V
BV_DSS	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250μA	40	-	-	V
g fs	Forward Transconductance	$V_{DS}=5V$, $I_D=4A$	-	12	-	S
IGSS	Gate-Source Leakage Current	V _{DS} =0V, V _{GS} =±20V	-	-	±100	nA
I _{DSS}	Drain-Source Leakage Current	V _{DS} =32V, V _{GS} =0V, T _J =25°C V _{DS} =32V, V _{GS} =0V, T _J =55°C	-	-	1 5	μA
R _{DS} (on)	Static Drain-Source On-Resistance ²	V _{GS} =10V, I _D =4.0A V _{GS} =4.5V, I _D =3.0A	-	-	32 45	mΩ
V _{SD}	Diode Forward Voltage ²	I _S =1.0A, V _{GS} =0V, T _J =25°C	-	-	1.2	V
Is	Continuous Source Current ^{1,4} (Diode)	V V 0V 5 0	-	-	5	
Ism	Pulsed Source Current ^{2,4} (Diode)	$V_G = V_D = 0V$, Force Current	-	-	16	A



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Dynamic and switching Characteristics						
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
Qg	Total Gate Charge ²	V _{DS} =15V		5.5		
Qgs	Gate-Source Charge	I _D =3A		1.25		nC
Qgd	Gate-Drain Charge	V _{GS} =4.5V		2.5		
td(on)	Turn-On Delay Time ²	V _{DS} =15V		8.9		
tr	Rise Time	I _D =1A		2.2		
td(off)	Turn-Off Delay Time	V _{GS} =4.5V		41		ns
tf	Fall Time	R _G =3.3Ω		2.7		
Ciss	Input Capacitance	V _{DS} =15V		593		
Coss	Output Capacitance	V _{GS} =0V		76		pF
Crss	Reverse Transfer Capacitance	f =1.0MHz		56		1

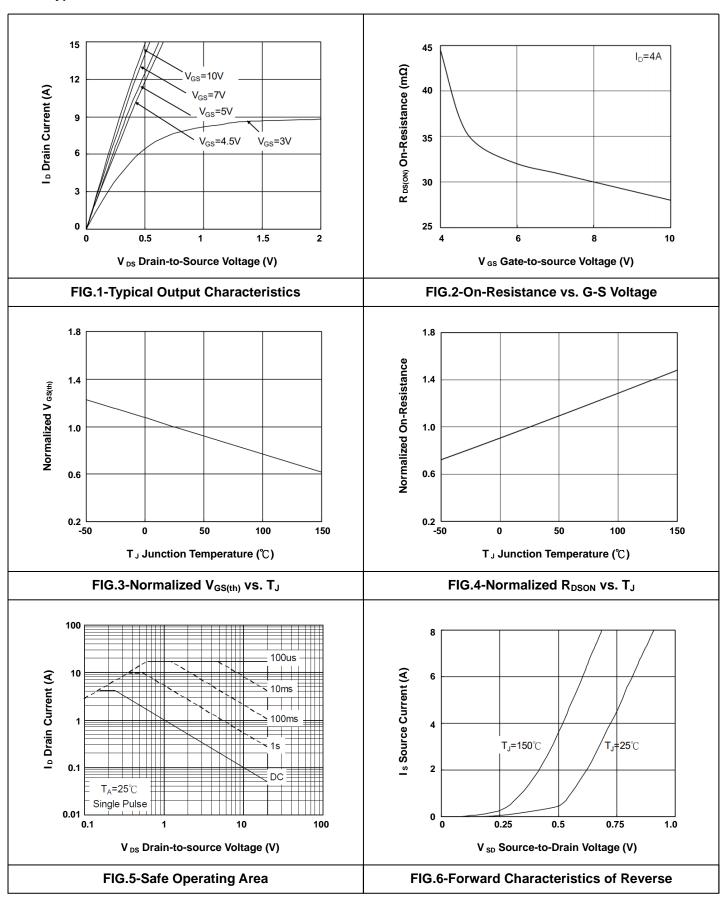
Notes

- 1. Surface mounted on a 1 inch² FR-4 board with 2OZ copper.
- 2. The data tested by pulsed, pulse width \leq 300us, duty cycle \leq 2%.
- 4. The data is theoretically the same as I_D and I_{DM} , in real applications, should be limited by total power dissipation.



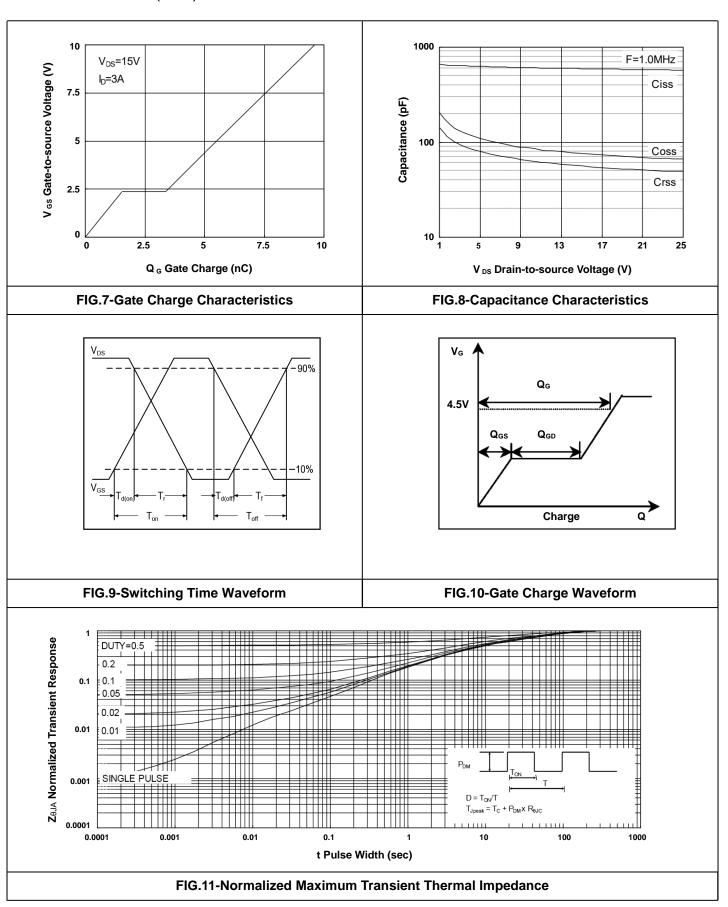
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• Typical Electrical Characteristics





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